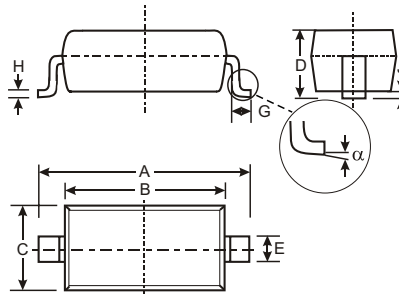


Features

- Schottky Barrier Chip
- Guard Ring Die Construction for Transient Protection
- Low Power Loss, High Efficiency
- High Surge Capability
- High Current Capability and Low Forward Voltage Drop
- For Use in Low Voltage, High Frequency Inverters, Free Wheeling, and Polarity Protection Application

Mechanical Data

- Case: SOD-123, Plastic
- Plastic Material: UL Flammability Classification Rating 94V-0
- Moisture sensitivity: Level 1 per J-STD-020A
- Polarity: Cathode Band
- Leads: Solderable per MIL-STD-202, Method 208
- Marking: Date Code and Type Code, See Page 3
- Type Code: SL
- Weight: 0.01 grams (approx.)
- Ordering Information: See Page 3



SOD-123		
Dim	Min	Max
A	3.55	3.85
B	2.55	2.85
C	1.40	1.70
D	—	1.35
E	0.55 Typical	
G	0.25	—
H	0.11 Typical	
J	—	0.10
α	0°	8°
All Dimensions in mm		

Maximum Ratings @ T_A = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	1N5819HW	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage @ I _R = 1.0mA DC Blocking Voltage	V _{RRM} V _{RWM} V _R	40	V
RMS Reverse Voltage	V _{R(RMS)}	28	V
Average Rectified Output Current @ T _L = 90°C	I _O	1.0	A
Non-Repetitive Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}	25	A
Power Dissipation (Note 2)	P _d	450	mW
Typical Thermal Resistance Junction to Ambient (Note 2)	R _{θJA}	222	°C/W
Operating and Storage Temperature Range	T _j , T _{STG}	-65 to +125	°C

Electrical Characteristics @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Breakdown Voltage (Note 1)	$V_{(BR)R}$	40	—	—	V	$I_R = 1.0\text{mA}$
Forward Voltage (Note 1)	V_F	—	—	0.320 0.450 0.750	V	$I_F = 0.1\text{A}$ $I_F = 1.0\text{A}$ $I_F = 3.0\text{A}$
Reverse Leakage Current (Note 1)	I_R	—	—	1.0 10 50 1 2 15 75 3	mA mA μA mA mA μA μA mA	$V_R = 40\text{V}, T_A = 25^\circ\text{C}$ $V_R = 40\text{V}, T_A = 100^\circ\text{C}$ $V_R = 4\text{V}, T_A = 25^\circ\text{C}$ $V_R = 4\text{V}, T_A = 100^\circ\text{C}$ $V_R = 6\text{V}, T_A = 25^\circ\text{C}$ $V_R = 6\text{V}, T_A = 100^\circ\text{C}$
Total Capacitance	C_T	—	110	—	pF	$V_R = 4\text{V}, f = 1.0\text{MHz}$

- Notes: 1. Short duration pulse test used to minimize self-heating effect.
 2. Device mounted on FR-4 PC Board, 2"x2", 2 oz. Copper, single sided, Cathode pad dimensions 0.75"x1.0", Anode pad dimensions 0.25"x1.0".

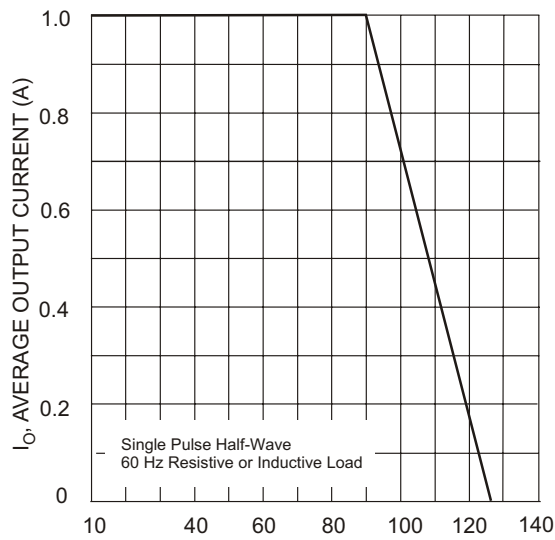


Fig. 1 Forward Current Derating Curve

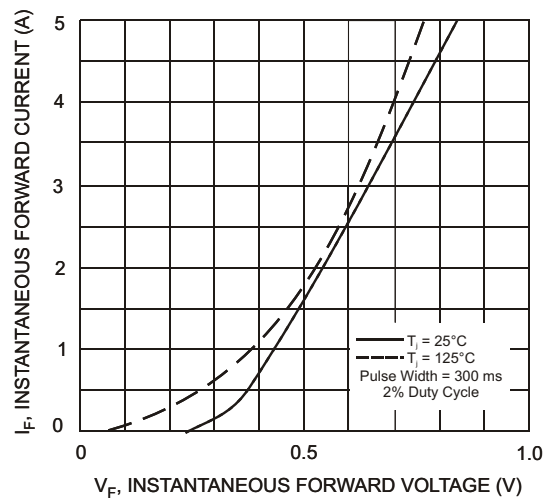


Fig. 2 Typical Forward Characteristics

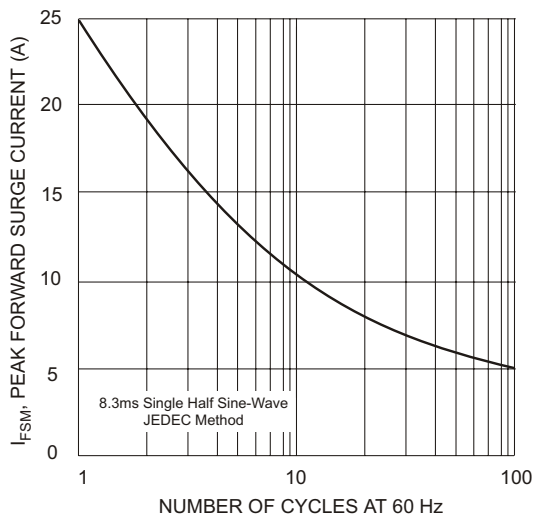


Fig. 3 Maximum Non-Repetitive Peak Fwd Surge Current

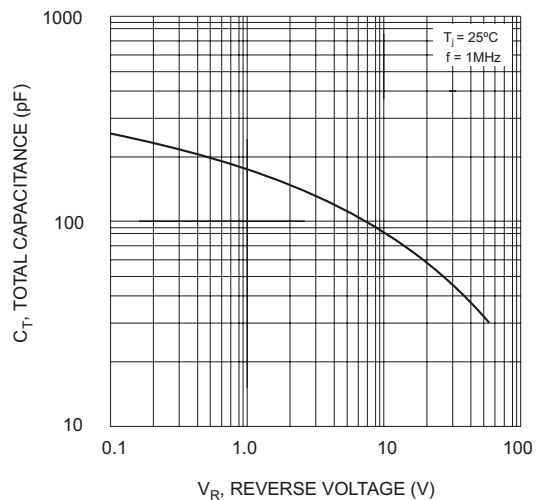


Fig. 4 Typical Total Capacitance

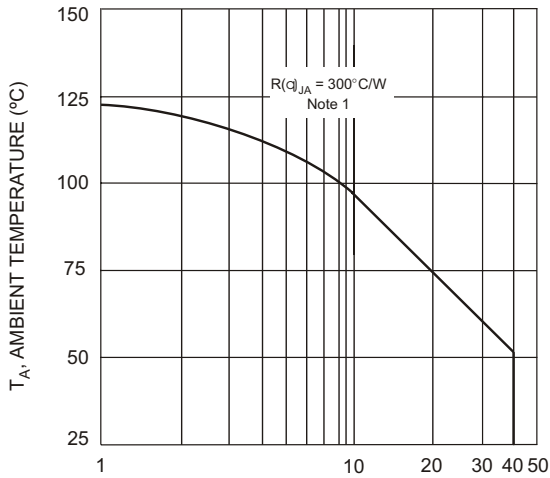


Fig. 5 Typical Safe Operating Area

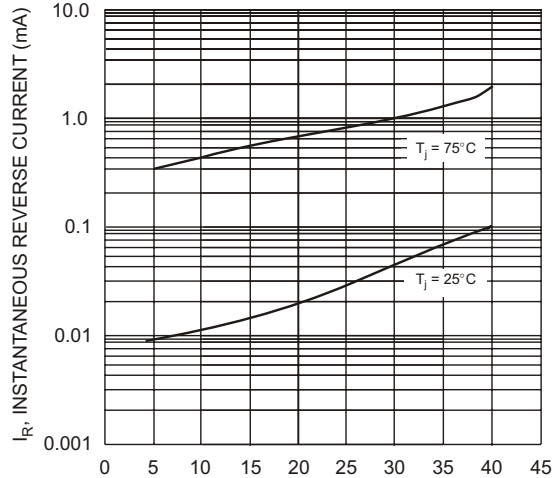


Fig. 6 Typical Reverse Characteristics

Ordering Information (Note 3)

Device	Packaging	Shipping
1N5819HW-7	SOD-123	3000/Tape & Reel

Notes: 3. For Packaging Details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.

Marking Information



XX = Product Type Marking Code
 YM = Date Code Marking
 Y = Year (ex: N = 2002)
 M = Month (ex: 9 = September)

Date Code Key

Year	2001	2002	2003	2004	2005	2006	2007	2008
Code	M	N	P	R	S	T	U	V

Month	Jan	Feb	March	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D